

ROHS

HALOGEN

FREE

Hyperfast Rectifier, 6 A FRED Pt®



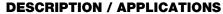


TO-252AA (D-PAK)

| PRODUCT SUMMARY | | | | |
|----------------------------------|------------------|--|--|--|
| Package | TO-252AA (D-PAK) | | | |
| I _{F(AV)} | 6 A | | | |
| V_{R} | 600 V | | | |
| V _F at I _F | 1.65 V | | | |
| t _{rr} (typ.) | 14 ns | | | |
| T _J max. | 175 °C | | | |
| Diode variation | Single die | | | |

FEATURES

- Hyperfast recovery time, extremely low Q_{rr}
- 175 °C maximum operating junction temperature
- For PFC CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---|-----------------------------------|---|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Peak repetitive reverse voltage | V_{RRM} | | 600 | V | |
| Average rectified forward current | I _{F(AV)} | T _C = 136 °C | 6 | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 50 | Α | |
| Peak repetitive forward current | I _{FM} | T _C = 136 °C, f = 20 kHz, d = 50 % | 12 | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|---|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS MIN. TY | | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 600 | - | - | |
| Forward voltage V _F | I _F = 6 A | - | 2.50 | 3.1 | V | |
| | I _F = 6 A, T _J = 150 °C | - | 1.65 | 1.9 | | |
| Dovorno logicogo gurrant | _ | $V_R = V_R$ rated | - | - | 20 | |
| Reverse leakage current I _R | | T _J = 150 °C, V _R = V _R rated | - | - | 250 | μA |
| Junction capacitance | C _T | V _R = 600 V | = | 3.5 | - | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body - 8 | | - | nH | |





| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|-------------------------|--|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | ı | 14 | 21 | |
| Reverse recovery time t _{rr} | + | $I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | i | 16 | - | ns |
| | T _J = 25 °C | | - | 19 | - | | |
| | T _J = 125 °C | | - | 27 | - | | |
| Peak recovery current I _{RRM} | 1 | T _J = 25 °C | $I_F = 6 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$ | - | 3.0 | - | А |
| | IRRM | T _J = 125 °C | | - | 4.0 | - | A |
| Reverse recovery charge | Q _{rr} | T _J = 25 °C | | - | 28 | - | nC |
| | | T _J = 125 °C | | - | 57 | - | 110 |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|-----------------------------|------|------|-------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C |
| Thermal resistance, junction to case per leg | R_{thJC} | | - | - | 3 | °C/W |
| Approximate weight | | | | 0.3 | | g |
| Approximate weight | | | | 0.01 | | OZ. |
| Marking device | | Case style TO-252AA (D-PAK) | | 6EWX | O6FNH | |

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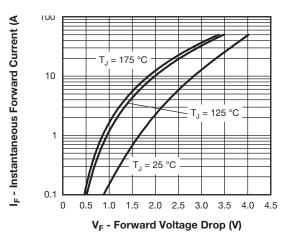


Fig. 1 - Typical Forward Voltage Drop Characteristics

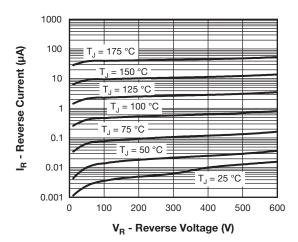


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

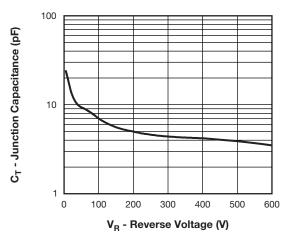


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

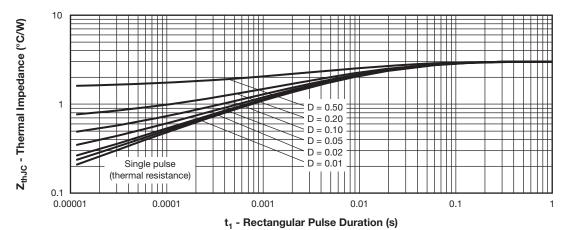


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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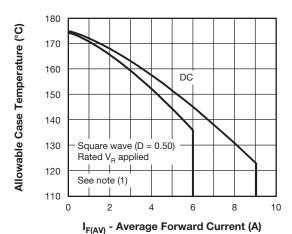


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

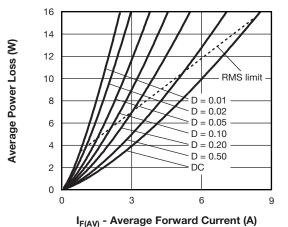


Fig. 6 - Forward Power Loss Characteristics

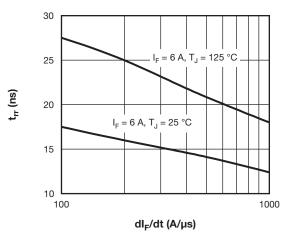


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

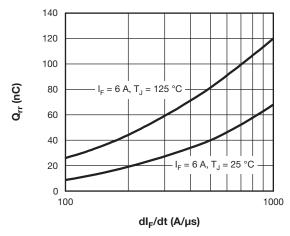


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$

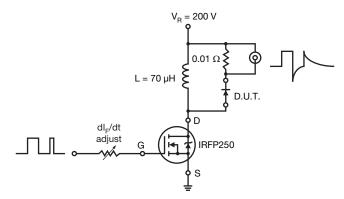
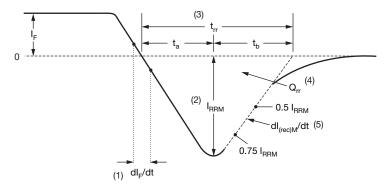


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) $\boldsymbol{I}_{\text{RRM}}$ peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RBM}$ and 0.50 $\rm I_{RBM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

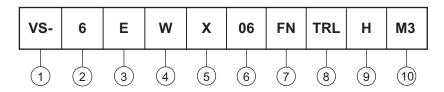
(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (6 = 6 A)

Circuit configuration:

E = single diode

4 - Package identifier:

W = D-PAK

5 - X = hyperfast recovery time

6 - Voltage rating (06 = 600 V)

7 - FN = TO-252AA

8 - • None = tube

TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

H = AEC-Q101 qualified

Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-6EWX06FNHM3 | 75 | 3000 | Antistatic plastic tube | | |
| VS-6EWX06FNTRHM3 | 2000 | 2000 | 13" diameter reel | | |
| VS-6EWX06FNTRRHM3 | 3000 | 3000 | 13" diameter reel | | |
| VS-6EWX06FNTRLHM3 | 3000 | 3000 | 13" diameter reel | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95519</u> | | | | |
| Part marking information | www.vishay.com/doc?95518 | | | |
| Packaging information | www.vishay.com/doc?95033 | | | |



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